



**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

Complete if Known

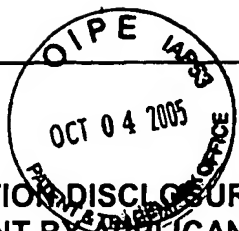
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Application Number	10/781,644
				Filing Date	February 20, 2004
				First Named Inventor	Won nam KANG
				Group Art Unit	1762
				Examiner Name	Brian K. Talbot
				Confirmation No.	3455
Sheet	1	of	2	Attorney Docket Number	1751-301.CON

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T ⁶
		Office ³ Code	Number ⁴	Kind ⁵ (if known)			
BT	1	WO	02/064859	A2	IOWA STATE UNIVERSITY RESEARCH FOUNDATION	08/22/2002	
Examiner Signature	BTalbot				Date Considered	12/14/05	

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code. ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language translation is attached. AB indicates that only an English language abstract is attached.



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NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²	
BT	2	KANG, W. et al., Epitaxial MgB2 Superconducting thin films with a transition temperature of 39 Kelvin, <i>Science</i> , 292, 1521 (March 8 2001); http://lanl.arxiv.org/abs/cond-mat/0103179 .	Abst.	
BT	3	KANG, W. et al., Epitaxial MgB2 Superconducting Thin Films with a Transition Temperature of 39 Kelvin, pp. 1-3 (March 9, 2001) (a copy of web pre-print at http://lanl.arxiv.org/abs/cond-mat/0103179).		
BT	4	KANG, W. et al., Epitaxial MgB2 Superconducting Thin Films with a Transition Temperature of 39 Kelvin, Los Alamos National Laboratory, Preprint Archive, Condensed Matter (March 9, 2001) (an STN search result from the Japanese Patent Office).	Abst.	
Examiner Signature	B. Talbot		Date Considered	12/14/05

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